First principles simulations of direct coexistence of solid and liquid alum inium

Dario Alfe

D epartm ent of E arth Sciences, and D epartm ent of P hysics and A stronom y, U niversity C ollege London, G ower Street, London, W C 1E 6BT, U K

F inst principles calculations based on density functional theory, with generalised gradient corrections and ultrasoft pseudopotentials, have been used to simulate solid and liquid alum inium in direct coexistence at zero pressure. Simulations have been carried out on systems containing up to 1000 atoms for 15 ps. The points on the melting curve extracted from these simulations are in very good agreement with previous calculations, which employed the same electronic structure method but used an approach based on the explicit calculation of free energies [1].

PACS numbers: 64.10.+ h 64.70 D v 71.15.-m 71.15.Pd

The calculation of melting properties of materials using computer simulations has a long history. Two main approaches have traditionally been used. The rst is based on the direct simulation of solid and liquid in coexistence $[2\{5,17\}]$. The second on the calculation of the free energy of solid and liquid [7{10,18}, with the melting point (p;T) determined by the condition of equality of the G ibbs free energies of liquid and solid, G $_{\rm liq}$ (p;T) = G_{sol}(p;T). The two approaches must clearly give the same answer once all the sources of errors have been brought under control. These works were originally carried out using classicalm odelpotentials, with param eters usually adjusted to reproduce som e known experim ental properties of the material, or tted to ab-initio calculations. The advantage of using these classical potentials is that they are relatively simple, so that computer simulations could easily be carried out on large system s and for long time. The main disadvantage, how ever, is that the transferability of these potentials is not always guaranteed, so that the accuracy of the predictions is som etim es questionable. In 1995 Sugino and Car [11] showed that it was actually possible to use density functional theory (DFT) [12] techniques to calculate the melting temperature of materials truly from st principles, i.e. without relying on any adjustable parameters. They chose the melting of silicon as a test case, and using the local density approximation (LDA) they calculated the G ibbs free energy of solid and liquid using therm odynam ic integration. This is a well known statistical mechanics technique to com pute free energy di erences between two systems [13]. The idea is to use a simple system for which the free energy is known as a reference system , and then com pute the free energy di erence between the ab-initio and the reference system, which is equal to the reversible work done in adiabatically switching the potential energy from one system to the other. An attractive feature of this method is that the nal result is totally independent on the choice of the reference system . In practice, how ever, this method can only work if one is able to nd a reference system which is as close as possible to the ab initio system, so that the computational e ort needed to calculate the free energy di erence between the two

system s is reduced to the m in im um . U sing this m ethod, Sugino and Car found a zero pressure melting tem perature about 20% lower than the experim ental datum . This may seem not particularly good, but it has to be remem bered that no adjustable param eters were inputed in the calculations, nor any experim ental data other than the Plank's constant and the mass and charge of the electron. Recently, we have argued [14] that this non-perfect agreem ent between LDA results and experiments is probably due to non-cancelling LDA errors between the solid and liquid. The reason is that the two phases have very di erent properties: the liquid is six-fold coordinated and the solid four-fold coordinated, the liquid is a metal and the solid an insulator, so it is not surprising that the LDA errors in the two phases m ay be di erent. W e have repeated the LDA calculations of Sugino and Car using sim ilar techniques and found the sam emelting temperature. How ever, we have also show n that if the generalised gradient corrections (GGA) are used, then the melting tem perature of silicon com es out in much closer agreem ent with the experim ents [14].

Since the work of Sugino and Car [11] a number of rst principles based calculations of melting points and melting curves have followed. In some cases the free energy approach has been used [15,16,19,20,1], while other m ethods relied on thing a model potential to rst principles simulations and calculating melting properties with the model potential $[3\{5]$. The advantage of the free energy approach is that it is unbiased, provided all sources of technical errors are brought under control. A disadvantage of the m ethod is that it is intrinsically com plex. On the other hand, the coexistence approach is relatively simple to apply, but has the main disadvantage of relying on good quality thing and, more in portantly, transferability of the model for at least a simultaneous good description of solid and liquid. Recently, we have shown that provided that them odelpotential is reasonably close to the ab-initio system [21], it is possible to correct for the (sm all) di erences between the model and the full ab-initio system using a perturbational approach to therm odynam ic integration, and that once the corrections are applied the results coincide with those obtained using the

free energy approach [22].

The coexistence approach has been used extensively in the past to calculate them elting properties of various materials. In the constant volum e constant internal energy (N VE ensemble) approach to the method it has been shown that liquid and solid can coexist for long time, provided V and E are appropriately chosen [2,22]. The average value of the pressure p and temperature T over the coexisting period then give a point on the melting curve. Size e ects have also been studied quite extensively, and it was shown that correct results can be obtained in system s containing more than 500 atom s [5,6].

Here I have exploited recent advances in computer power and algorithms developments to use direct DFT calculations for simulating solid and liquid alum inium in coexistence near zero pressure. This work combines the simplicity of the coexistence approach with the accuracy provided by DFT, and in some respect represents a shift of paradigm, whereby the main e ort is transferred from the hum an to the computer. The temperature at which solid and liquid coexist are found to be in good agreement with our previous results obtained with the free energy approach [1], so that these results also provide additional evidence that our techniques to calculate free energies are sound.

The calculations have been performed with the VASP code [23], with the implementation of an e cient extrapolation of the charge density [24], ultrasoft pseudopotentials [25] with a plane wave cuto of 130 eV, and generalised gradient corrections. The simulations have been performed in the NVE ensemble on systems containing 1000 atoms (5 5 10 cubic supercell), with a time step of 3 fs and a convergency threshold on the total energy of 2 10 7 eV /atom . W ith these prescriptions the drift in the microcanonical total energy was less than 0:3 K /ps. The total length of the simulations were typically 15 ps. The volume per atom was chosen to be V = $185 A^3$, which is close to the average of the volum es of solid and liquid at the zero pressure melting point calculated in our previous work [1]. Electronic excitations have been included within the fram ework of nite temperature DFT. The simulations have been perform ed using the point only, and spot checked with Monkhorst-Pack [26] (2 2 1) and (4 4 2) k-point grids. Calculations with the point predict a small non-hydrostatic stress tensor with a di erence of $(p_x + p_y)=2 = 2 \text{ kB}$ between the compoabout p_z nents of the stress parallel to the solid-liquid interface, p_x and p_y , and that perpendicular to the interface, p_z . The pressure $p = (p_x + p_y + p_z)=3$ is essentially exact and the three o -diagonal components of the stress tensor

uctuate around zero average, so that there is no shear stress on the cell. W ith the total energy is wrong by 5 m eV/atom, and it is likely that the error is alm ost equally shared by the liquid and the solid parts, so that the resulting error on the melting temperature is most probably negligible [27]. A correction term of 2.7 kB due to the lack of convergency with respect to the plane wave cuto has been added to the calculated pressures. The system s have been monitored by inspecting the average num ber density in slices of the cell taken parallel to the boundary between solid and liquid. In the solid region this num ber is a periodic function of the slice num ber, and in the liquid part it uctuates random ly around its average value.

The zero pressure crystal structure of alum inium is face-centred-cube (fcc), so I have assumed that melting occurs from this structure. To prepare the system I have used the inverse power classical potential employed in Ref. [1]. Thism odel has been tuned to the same ab-initio system used here, so it is a good starting point for the present calculations. The preparation procedure follows Ref. [2]. A perfect crystal is initially therm alized at 800 K, then the simulation is stopped, half of the atom s are clamped and the other half are freely evolved at very high tem perature untilmelting occurs, then the liquid is therm alized back at 800 K [28]. At this point the system is being freely evolved in the N VE ensem ble using D FT.

A s explained in R ef. [22], for each chosen volum e there is a whole range of internal energies for which di erent am ount of solid and liquid are in coexistence. Provided that the energy is not too low (high) so that that the whole system freezes (melts), a whole piece of melting curve can be obtained for any xed volume. In this work I have perform ed 3 simulations with 1000 atom s, all at the sam e volum e but with di erent am ounts of total energy, which therefore provide three distinct points on the melting curve. In all simulations coexistence was obtained for the whole length of the runs. In Fig. 1 I display the density pro le, calculated by dividing the simulations cell. into 100 slices parallel to the solid-liquid interface, corresponding to the last con guration of one of these simulations. Fig. 2 contains the calculated tem perature (upper panel) and pressure (low er panel) for this particular sim ulation, and shows that they oscillate stably around their average values T 820 K and p 5:5 kB [29]. In order to test the reliability of the lengths of these simulations I have perform ed additional runs on system containing 512 atom s (4 4 10 cubic supercell), which could be sim ulated for up to 40 ps. Tem perature and pressure from one of these runs are displayed in Fig. 3. It is clear that all the information needed to extract useful values for p and T is contained in any time window of 5 10 ps, which provides con dence that the simulations for the large system s are long enough. A more detailed inspection of the

gures reveals the presence of anti-correlated oscillations in pressure and temperature, which correspond to uctuations in the total amount of solid and liquid in the system. These uctuations seem absent in the simulations with 1000 atoms, but they would probably develop if the runs could be extended. In any case, they do not a ect the average value of p and T.

It has been pointed out that non-hydrostaic conditions arti cially raise the free energy of the solid, and therefore lower the melting temperature [6]. To investigate the e ect on the melting temperature due to the present non-hydrostatic conditions I have used the model potential used in Ref. [1]. The model showed a di erence $(p_x + p_y) = 2 = 0.5$ kB when simulated with the same p_7 cellas the ab-initio system with 1000 atoms. To estimate the system atic error on the melting temperature I have perform ed an additional simulation using a slightly elongated cellat the sam e volum e, so that non-hydrostaticity was reduced to less than 0.1 kB. The decrease of melting tem perature in this second simulation was less than 10 K.A similare ect is expected for the ab-initio system, so that I estim ate a system atic error due to non-hydrostatic conditions to be at worse of the order of 20 K.

In Fig. 4 I report the values of p and T calculated here in comparison with the low end of the melting curve calculated in Ref. [1] The agreem ent between the present nding with 1000 atoms and the free energy approach results is extremely good. The results obtained from the simulations with 512 atoms display melting temperatures higher by about 50 K, although they are still com patible with the results obtained with the free energy approach within the combined error bars. In order to test if the cause of this size e ect was due to inadequate k-point sam pling, I have perform ed a sim ulation using a $(2 \ 2 \ 1)$ k-point grid on a system with 512 atoms for 6 ps. The length of this simulation is too short to draw de nite conclusions, but it indicates that the pressure may be underestim ated by 1 2 kB and the tem perature over-predicted by 20 K. This would bring the results in som ew hat better agreem ent with those obtained with the larger system, and also with the calculations based on the free energy approach (which were fully converged with respect to size and k-point sampling) [1]. Notice that these results do not agree perfectly with the experim ental zero pressure m elting tem perature of alum inium (933 K) [30]. We have argued in our previous work [1] that this disagreem ent is due to inadequacy of the GGA to predict the vibrational properties of the solid. We have also suggested that this inaccuracy can be rationalised in terms of the errors in the equation of state, and devised a simple way to correct for it. In Table 1 I report the calculated GGA lattice constant, the bulk modulus and the cohesive energy com pared with the experim ental data. Following Gaudoin et al. [32], I also report the experim ental values adjusted for the absence of zero point motion e ects, which is missing in the present calculated values. It is evident that the GGA predicts a zero pressure lattice constant for Alwhich is too large, or, which m eans that at the correct lattice constant GGA predicts a positive pressure of about 16 kB. It follows that the GGA zero pressure melting point is actually the melting point at a negative pressure of about -16 kB, which is about 120-130 K lower.

In sum m ary, I have show n here that it has become possible to directly simulate solid and liquid in coexistence using density functional theory techniques. This method com bines the advantages of being relative easy to use and provide DFT accuracy. It is inevitably computationally very intensive, and these calculations have only been possible thanks to an access onto the 3.5 Tera op/sm achine (IBM p690 Regatta with 1280 processors). The cost of each molecular dynamics step for the 1000 atoms system was between 3 and 4 m inutes on 128 processors of the machine. However, as large computer resources becom e routinely available this method should nd widespread applicability in the future. The present results are in very good agreement with our previous ndings based on the direct calculations of free energies, and therefore also support the reliability of those techniques.

This work has been supported by the Royal Society and by the Leverhulm e Trust. The author wishes to acknow ledge the computational facilities of the UCL HiPerSPACE Centre (JREI grant JR 98UCGI), and the early access to the HPCx computer facilities in D aresbury, granted by NERC through support of the M ineral Physics Consortium. The author is grateful to C.W right for computational technical support and to M.J.G illan and G.D.Price for discussions. The authorals wishes to thank M.Pozzo for useful suggestions on the manuscript.

- [1] L.Vocadlo and D.Alfe, Phys.Rev.B, 65, 214105 (2002).
- [2] J. R. Morris, C. Z. W ang, K. M. Ho, and C. T. Chan, Phys. Rev. B 49, 3109 (1994).
- [3] A. Laio, S. Bernard, G. L. Chiarotti, S. Scandolo and E. Tosatti, Science 287, 1027 (2000).
- [4] A. B. Belonoshko, R. Ahuja, and B. Johansson, Phys. Rev. Lett. 84, 3638 (2000).
- [5] A.B.Belonoshko, R.Ahuja, O.Eriksson, and B.Johansson, Phys. Rev. B 61, 3838 (2000).
- [6] J.R.Morris, X.Song, J.Chem. Phys., 116, 9352 (2002).
- [7] J.A.M oriarty, D.A.Young, and M.Ross, Phys. Rev.B 30, 578 (1984).
- [8] J.Q.Broughton, X.P.Li, Phys. Rev. B, 35, 9120 (1987).
- [9] J.M ei, J.W .D avenport, Phys. Rev. B 46, 21 (1992).
- [10] G.K.Straub, J.B.Aidun, J.M.W illis, C.R.Sanchez-Castro, and D.C.W allace, Phys. Rev. B 50, 5055 (1994).
- [11] O.Sugino and R.Car, Phys. Rev. Lett. 74, 1823 (1995).
- [12] R. Car and M. Parrinello, Phys. Rev. Lett. 55, 2471 (1985).
- [13] For a discussion of therm odynam ic integration see e.g. D.Frenkel and B.Sm it, Understanding M olecular Simulation, A cadem ic Press, San Diego (1996).
- [14] D.Alfe and M.J.Gillan, Phys. Rev.B., (in press).
- [15] G.A.deW ijs, G.K resse and M.J.Gillan, Phys. Rev. B 57, 8223 (1998).
- [16] D.Alfe, M.J.Gillan and G.D.Price, Nature 401, 462

(1999).

- [17] B. J. Jesson and P. A. Madden, J. of Chem. Phy. 113 5935 (2000).
- [18] B.J. Jesson and P.A. Madden, J. of Chem. Phy. 113 5924 (2000).
- [19] D. Alfe, G. D. Price, M. J. Gillan, Phys. Rev. B, 64, 045123 (2001).
- [20] D. Alfe, G. D. Price, M. J. Gillan, Phys. Rev. B, 65, 165118 (2002).
- [21] The distance between the model potential and the abinitio system at a chosen them odynamic state can be de ned as the magnitude of the uctuations in the difference of the respective internal energies. See Ref. [22] for more details.
- [22] D. A lfe, G. D. Price, M. J. Gillan, J. Chem. Phys, 116, 7127 (2002).
- [23] G. K resse and J. Furthm uller, Phys. Rev. B, 54, 11169 (1996); G. K resse and J. Furthm uller, C om put. M ater. Sci., 6, 15 (1996); a discussion of the ultra-soft pseudopotentials used in the VA SP code is given in G. K resse and J. H afner, J. Phys. C ondens. M atter, 6, 8245 (1994).
- [24] D.Alfe, Computer Phys.Commun., 118, 31 (1999).
- [25] D. Vanderbilt, Phys. Rev. B, 41, 7892 (1990).
- [26] H.J.M onkhorst and J.D.Pack, Phys. Rev. B 13, 5188 (1976).
- [27] Even in the unlikely worse case scenario in which this error was borne entirely by the solid (or entirely by the liquid), this would result in a wrong prediction of the m elting temperature by only about 30 K.
- [28] The tem perature of 800 K has been chosen because it is close to the DFT-GGA melting tem perature previously calculated [1].
- [29] In fact, the simulation reported in Fig. 2 has been spawn from a previously well equilibrated simulation with a different value of total energy. The time needed to equilibrate the system the rst time ab-initio was switched on from the classical regime was about 1 ps.
- [30] CRC Handbook of Chemistry and Physics, Editor D.R. Lide, New York, 77th edition (1996–1997).
- [31] C. K ittel, Introduction to solid state physics, 7th edn (N ew York: W iley), 1996.
- [32] R. Gaudoin, W. M. C. Foulkes and G. Rajagopal, J. Phys: Condens. Matter 14 8787 (2002).
- [33] F.Birch, Phys. Rev. 71 809 (1947).

	E xperim ent	GGA
Е	3.39 (3.43)	3.43
В	76 (81)	73
a_0	4.049 (4.022)	4.05

TABLE I. Experimental values for the cohesive energy E^{c} (eV/atom) [31], the bulk modulus B (GPa) [30] and the lattice constant a_0 (A) [30]. In parenthesis are the adjusted values for the e ect of zero point motion [32]. The calculated GGA values have been obtained from a t to a B irch-M umaghan equation of state [33], and they do not include zero point motion e ects.

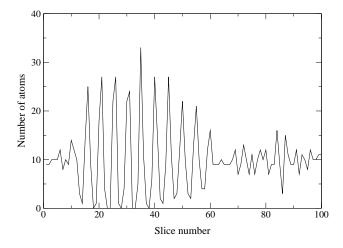


FIG.1. Density pro le in a simulation of solid and liquid Al coexisting at zero pressure. The system is divided in slices of equal thickness (0.42 A) parallel to the solid-liquid interface, and the graph shows number of atom s in each slice. Simulations were performed on a system of 1000 atom s using density functional theory.

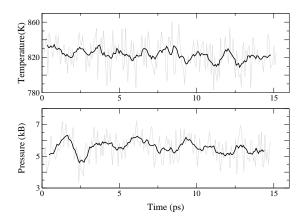


FIG.2. T in e variation of tem perature (upper panel) and pressure (low er panel) during a simulation of solid and liquid A l in coexistence. Simulations were performed on a system of 1000 atom s with density functional theory. G ray lines: actual data; black lines: running averages over a 0.75 ps period.

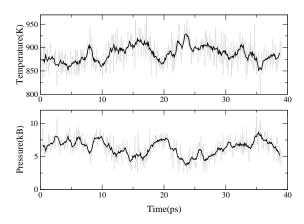


FIG.3. T in e variation of tem perature (upper panel) and pressure (low er panel) during a simulation of solid and liquid Al in coexistence for a system containing 512 atoms. Gray lines: actual data; black lines: running averages over a 0.75 ps period.

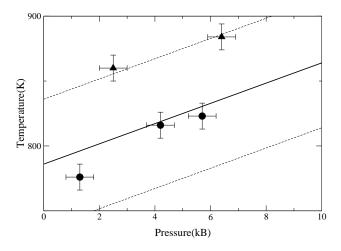


FIG.4. Temperatures and pressures at which liquid and solid coexist in simulations containing 1000 atoms (circles) and 512 atoms (triangles). The solid line is the lower end of the melting curve calculated using the free energy approach in R ef. [1] (see text), light dashed lines represent error bars.